

Docket No.: 57810-033

PATENT

2818

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Nobuhiko HAYASHI, et al.

Serial No.: 10/084,050

Filed: February 28, 2002

For: NITRIDE-BASED SEMICONDUCTOR ELEMENT AND METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR



Customer Number: 20277

Confirmation Number: 6460

Group Art Unit: 2818

Examiner: Dung A. Le

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Mail Stop Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

Transmitted herewith is an Amendment in the above-identified application.

☐  
☐  
☐

No additional fee is required.

Applicant is entitled to small entity status under 37 CFR 1.27

Also attached:

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	28	28	0	\$18.00 =	\$0.00
Independent Claims	6	6	0	\$84.00 =	\$0.00
Multiple claims newly presented					\$0.00
Fee for extension of time					\$110.00
Total of Above Calculations					\$0.00
					\$110.00

- ☒ Please charge my Deposit Account No. 500417 in the amount of \$110.00. An additional copy of this transmittal sheet is submitted herewith.
- ☒ The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

Arthur J. Steiner

Registration No. 26,106

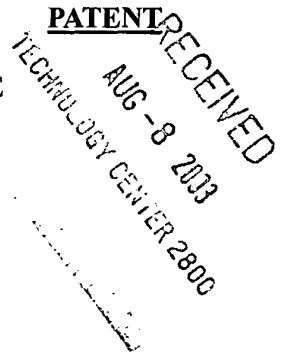
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Date: August 6, 2003

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In re Application of	:	Customer Number: 20277
Nobuhiko HAYASHI, et al.	:	Confirmation Number: 6460
Serial No.: 10/084,050	:	Group Art Unit: 2818
Filed: February 28, 2002	:	Examiner: Dung A. Le
For:	:	
NITRIDE-BASED SEMICONDUCTOR ELEMENT AND METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR		



**AMENDMENT**

Mail Stop Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

The following Amendment and Remarks are submitted in response to the Office Action dated April 18, 2003 which superceded the previous Office Action dated April 11, 2003.